Review of: "Nanotechnology is the field of application of extremely small components next to each other. In the case of computers, the goal of putting these nanometer components together is to build faster, more powerful and smoother functioning computers in a smaller volume"

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Making wires in nanometer dimensions is very interesting both from a technological and scientific point of view, because they show unusual properties in nanometer dimensions. The ratio of length to diameter of nanowires is very high.

Nanotechnology is the field of application of extremely small components next to each other. In the case of computers, the goal of putting these nanometer components together is to build faster, more powerful and smoother functioning computers in a smaller volume, which are used in nano-microelectronics systems. Nanotechnology has and will play a major role in the design scenario of newer and faster computers. One of the industries that benefit the most from the growth of nanotechnology is the electronics industry. The design of computers and their parts is such that they continuously move towards reducing and optimizing the dimensions of the parts. In such a situation, the role of nanotechnology in the computer can turn the eyes towards itself. Electronic nanotechnology is widely used in computers and electronic components. Nanotechnology is the study of particles at the atomic scale to control them. The main goal of most nanotechnology research is to form new compounds or make changes in existing materials. By using nanostructures, the size of memory bits can be basically reduced, thus increasing the density of magnetic memory and its efficiency, and lowering its cost. Nano lithography methods are now being used to prepare some very powerful memories.

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